

SEMITRANS® 3

IGBT4 Modules

SKM500GB17E4

Features*

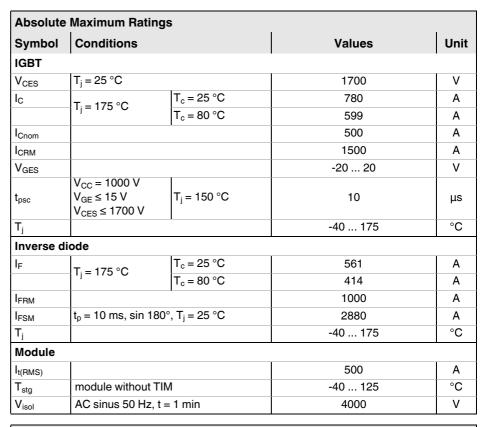
- IGBT4 = 4th generation medium fast trench IGBT (Infineon)
- CAL4 = Soft switching 4th generation CAL-Diode
- Insulated copper baseplate using DBC Technology (Direct Copper Bonding)
- With integrated Gate resistor
- For switching frequencies up to 8kHz
- UL recognized, file no. E63532

Typical Applications

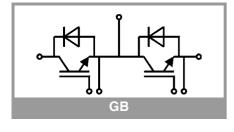
- AC inverter drives
- UPS

Remarks

- Case temperature limited to T_C = 125°C max
- Recommended $T_{j,op} = -40 \dots +150$ °C
- Product reliability results valid for T_j = 150°C



Characteristics									
Symbol	Conditions	min.	typ.	max.	Unit				
IGBT						•			
V _{CE(sat)}	I _C = 500 A V _{GE} = 15 V chiplevel	T _j = 25 °C		1.90	2.20	٧			
		T _j = 150 °C		2.45	2.80	٧			
V _{CE0}	chiplevel	T _j = 25 °C		1.00	1.10	٧			
		T _j = 150 °C		0.90	1.00	V			
r _{CE}	V _{GE} = 15 V chiplevel	T _j = 25 °C		1.80	2.2	mΩ			
		T _j = 150 °C		3.1	3.6	mΩ			
$V_{GE(th)}$	$V_{GE}=V_{CE}$, $I_{C}=20$ mA		5.2	5.8	6.4	V			
I _{CES}	V _{GE} = 0 V V _{CE} = 1700 V	T _j = 25 °C			5	mA			
		T _j = 150 °C		-		mA			
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		40.4		nF			
C _{oes}		f = 1 MHz		1.60		nF			
C _{res}		f = 1 MHz		1.48		nF			
Q _G	V _{GE} = - 8 V+ 15 V			4000		nC			
R _{Gint}	T _j = 25 °C			1.0		Ω			
t _{d(on)}	$\begin{array}{c} V_{CC} = 1200 \ V \\ I_C = 500 \ A \\ V_{GE} = +15/\text{-}15 \ V \\ R_{G \ on} = 2 \ \Omega \\ R_{G \ off} = 1 \ \Omega \\ di/dt_{on} = 12500 \ A/ \\ \mu s \\ di/dt_{off} = 2400 \ A/\mu s \\ dv/dt = 2050 \ V/\mu s \\ L_s = 25 \ nH \end{array}$	T _j = 150 °C		190		ns			
t _r		T _j = 150 °C		50		ns			
Eon		T _j = 150 °C		135		mJ			
t _{d(off)}		T _j = 150 °C		760		ns			
t _f		T _j = 150 °C		160		ns			
E _{off}		T _j = 150 °C		210		mJ			
R _{th(j-c)}	per IGBT			0.048	K/W				





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Typical Applications

· AC inverter drives

• UPS

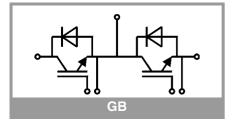
Remarks

• Case temperature limited to $T_C = 125$ °C

• Recommended $T_{j,op}$ = -40 ... +150°C

Product reliability results valid for T_i = 150°C

Characteristics										
Symbol	Conditions	min.	typ.	max.	Unit					
Inverse diode										
$V_F = V_{EC}$	I _F = 500 A	T _j = 25 °C		1.99	2.38	V				
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.13	2.54	V				
V_{F0}	chiplevel	T _j = 25 °C		1.32	1.56	V				
		T _j = 150 °C		1.08	1.22	V				
r _F	chiplevel	T _j = 25 °C		1.34	1.64	mΩ				
		T _j = 150 °C		2.1	2.6	mΩ				
I _{RRM}	$\begin{split} I_F &= 500 \text{ A} \\ \text{di/dt}_{\text{off}} &= 9750 \text{ A/}\mu\text{s} \\ V_{GE} &= -15 \text{ V} \\ V_{CC} &= 1200 \text{ V} \\ L_s &= 25 \text{ nH} \end{split}$	T _j = 150 °C		705		Α				
Q _{rr}		T _j = 150 °C		165		μC				
E _{rr}		T _j = 150 °C		130		mJ				
R _{th(j-c)}	per diode				0.103	K/W				
Module										
L _{CE}				15		nΗ				
R _{CC'+EE'}	measured per	T _C = 25 °C		0.55		mΩ				
	switch	T _C = 125 °C		0.85		mΩ				
R _{th(c-s)}	per module			0.02	0.038	K/W				
Ms	to heat sink M6		3		5	Nm				
Mt		to terminals M6	2.5		5	Nm				
				-		Nm				
w					325	g				



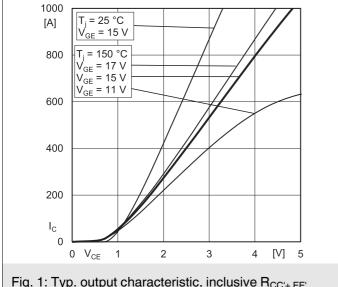


Fig. 1: Typ. output characteristic, inclusive R_{CC'+ EE'}

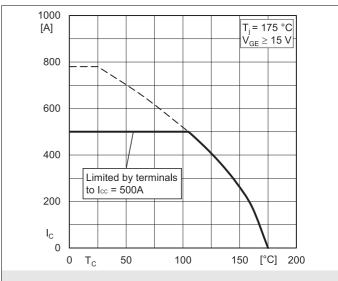


Fig. 2: Rated current vs. temperature $I_C = f(T_C)$

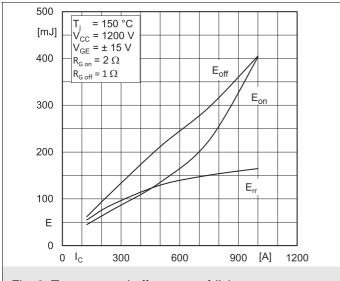


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

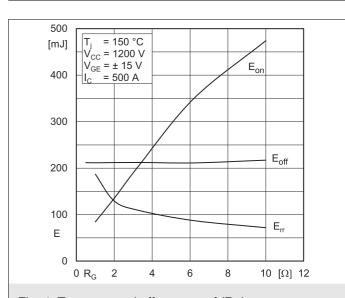


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

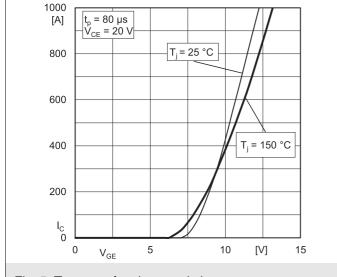


Fig. 5: Typ. transfer characteristic

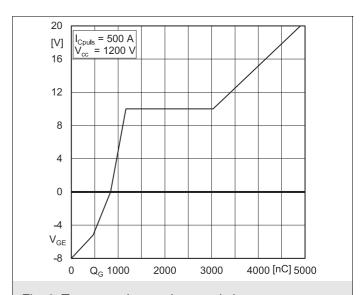
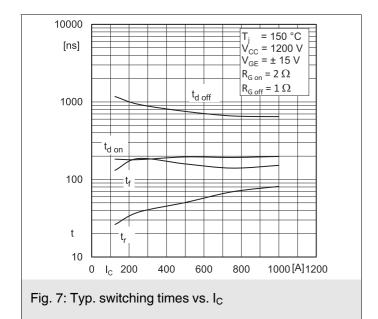
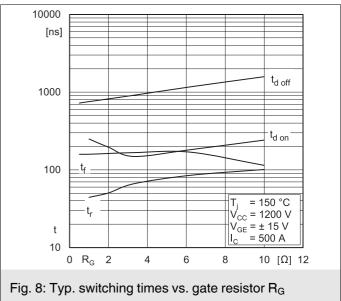
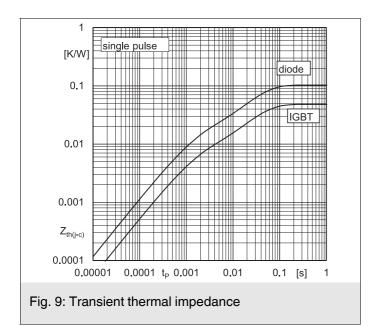
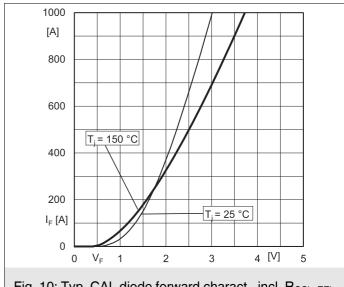


Fig. 6: Typ. gate charge characteristic









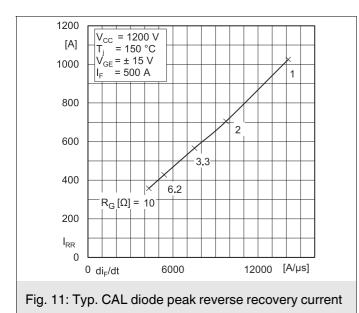


Fig. 10: Typ. CAL diode forward charact., incl. $R_{\text{CC'+} \text{ EE'}}$

 $V_{CC} = 1200 \text{ V}$

 $V_{GE} = \pm 15 \text{ V}$

di_F/dt

= 150 °C

10 6.2 3.3 2

6000

[µC]

300

200

100

 Q_{rr}



1000

750

500

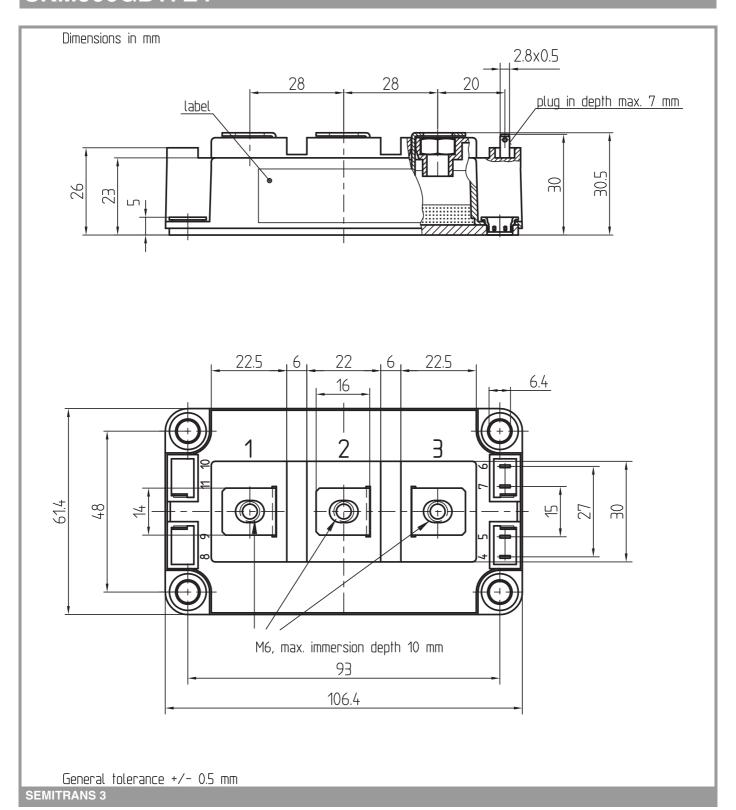
[A/µs] 18000

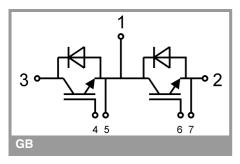
250

 $125 = I_F[A]$

 $=R_G[\Omega]$

12000





This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

*IMPORTANT INFORMATION AND WARNINGS

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